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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/832,892	04/12/2001	Takehisa Yamaguchi	205975US2	1675
22850	7590 11/06/2006	•	EXAMINER	
C. IRVIN MCCLELLAND			NGUYEN	, HOAN C
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C. 1940 DUKE STREET ALEXANDRIA, VA 22314			ART UNIT	PAPER NUMBER
			2871	

DATE MAILED: 11/06/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/832,892	YAMAGUCHI ET AL.				
Office Action Summary	Examiner	Art Unit				
	HOAN C. NGUYEN	2871				
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet w	ith the correspondence address				
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNI (36(a). In no event, however, may a will apply and will expire SIX (6) MON (a) cause the application to become A	CATION. reply be timely filed ITHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 22 S	September 2006.					
· · · · · · · · · · · · · · · · · · ·	s action is non-final.					
3) Since this application is in condition for allowa	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under t	Ex parte Quayle, 1935 C.D). 11, 453 O.G. 213.				
Disposition of Claims						
4) Claim(s) 1-13 is/are pending in the application	4)⊠ Claim(s) <u>1-13</u> is/are pending in the application.					
4a) Of the above claim(s) <u>6-13</u> is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.	5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-5</u> is/are rejected.	6) Claim(s) 1-5 is/are rejected.					
7) Claim(s) is/are objected to.	Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	or election requirement.					
Application Papers						
9)☐ The specification is objected to by the Examine	er.					
10) The drawing(s) filed on is/are: a) acc	cepted or b) objected to	by the Examiner.				
Applicant may not request that any objection to the	drawing(s) be held in abeya	nce. See 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the correct	tion is required if the drawing	(s) is objected to. See 37 CFR 1.121(d).				
11) The oath or declaration is objected to by the E	xaminer. Note the attache	d Office Action or form PTO-152.				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreigr a) All b) Some * c) None of:	n priority under 35 U.S.C.	§ 119(a)-(d) or (f).				
1. Certified copies of the priority document	ts have been received.					
2. Certified copies of the priority document		Application No				
3. Copies of the certified copies of the price	ority documents have beer	received in this National Stage				
application from the International Burea	u (PCT Rule 17.2(a)).					
* See the attached detailed Office action for a list	of the certified copies not	received.				
Attachment(c)	•					
Attachment(s) 1) Notice of References Cited (PTO-892)	4) Interview	Summary (PTO-413)				
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No	s)/Mail Date				
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 9/21/06.	5) Notice of Informal Patent Application 6) Other:					

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after allowance or after an Office action under *Ex Parte Quayle*, 25 USPQ 74, 453 O.G. 213 (Comm'r Pat. 1935). Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, prosecution in this application has been reopened pursuant to 37 CFR 1.114. Applicant's submission filed on 9/21/2006 has been entered.

On 09/21/2006, applicants withdraw from issue for submitting the translation of a part of Korean Patent Publication No. 0079893/1999, in which the names of drain electrode and source electrode have been reversed (source electrode being drain electrode and drain electrode being source electrode).

Due to new prior 0079893/1999 submitted by applicants, the allowance mailed on 5/12/2004 is withdrawn.

This rejection is based on the response for after final filed on 09/02/2003. Therefore, the only claims 1-5 are considered, the non-elected claims 6-13 are withdrawn as before.

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

1. Claims 1-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over Takashi (JP1267617) in view of prior art of 0079893/1999 submitted by application in IDS.

Takaki teaches (Fig. 1) a liquid crystal display comprising:

- a gate electrode line 106 including a gate electrode formed on an insulating substrate;
- a source electrode line 108 including a source electrode103 intersected with said gate electrode line 106 via an insulating film (gate insulating film 105);
- a thin film transistor including said gate electrode, said source electrode, and two
 drain electrodes located in a vicinity of a portion in which said gate electrode line
 is intersected with said source electrode line;
- two drain electrode lines 102, each including a portion acting as one of the two drain electrodes, said two drain electrode lines being connected with a pixel electrode 107;

wherein

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said two drain electrodes are located on opposite sides of said source electrode
with each of said two drain electrodes having a near side opposed to said source
electrode that is superposed with said gate electrode and a far side opposed to
near side that is not superposed with said gate electrode.

Claim 2:

an area of a region where said gate electrode line 106 is superposed with the
near side of one of said two drain electrodes is substantially identical to an area
of a region where said gate electrode is superposed with the other one of said
two drain electrodes as shown in Fig. 1b.

Claim 3:

a length of a region in a channel lengthwise direction of said thin film transistor
where said gate electrode is superposed with the near side of one of said two
drain electrodes is substantially identical to a length 109 of a region in a channel
lengthwise direction of said thin film transistor where said gate electrode line is
superposed with the near side of other one of said two drain electrodes,

Claim 5:

 said two drain electrodes are formed in whole part of one end of said drain electrode line in a channel widthwise direction where the near side of each drain electrode is superposed with said gate electrode line;

However, Takashi (JP1267617) fails to disclose each of two drain electrodes having (a) a near side facing in parallel with source electrode; and being superposed

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with the gate electrode; a far side opposed to and in parallel with the near side; and not being superposed with the gate electrode with the property stated in claim 4.

Prior art of 0079893/1999 teaches each of two drain electrodes having a near side facing in parallel with source electrode; and being superposed with the gate electrode; a far side opposed to and in parallel with the near side; and not being superposed with the gate electrode for minimizing of deviation of kickback voltage, thus said length of the region in the channel lengthwise direction is such a length for preventing current characteristics from degradation in a thin film transistor.

Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to further modify a liquid crystal display device as Takashi disclosed with each of two drain electrodes having a near side facing in parallel with source electrode; and being superposed with the gate electrode; a far side opposed to and in parallel with the near side; and not being superposed with the gate electrode for minimizing of deviation of kickback voltage as taught by prior art of 0079893/1999, thus, said length of the region in the channel lengthwise direction is such a length for preventing current characteristics from degradation in a thin film transistor.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to HOAN C. NGUYEN whose telephone number is (571)

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272-2296. The examiner can normally be reached on MONDAY-THURSDAY:8:00AM-4:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

HOAN C. NGUYEN Examiner Art Unit 2871

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Andrew schechter Primary examiner